

Nch 600V 25A Power MOSFET

V _{DSS}	600V
R _{DS(on)} (Max.)	0.182Ω
I _D	±25A
P _D	85W

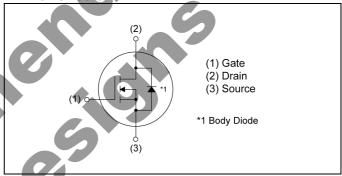
Outline



Features

- 1) Fast reverse recovery time (trr)
- 2) Low on-resistance
- 3) Fast switching speed
- 4) Drive circuits can be simple
- 5) Pb-free plating; RoHS compliant

●Inner circuit



Application

Switching

Packaging specifications

<u> </u>	
Packing	Tube
Packing code	C8
Marking	R6025JNZ
Basic ordering unit (pcs)	360

● Absolute maximum ratings (T_a = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	600	V
Continuous drain current (T _c = 25°C)	I _D *1	±25	А
Pulsed drain current	l _{DP} *2	±75	А
Gate - Source voltage	V_{GSS}	±30	V
Avalanche current, single pulse	I _{AS} *3	5.0	А
Avalanche energy, single pulse	E _{AS} *3	682	mJ
Power dissipation (T _c = 25°C)	P _D	85	W
Junction temperature	T _j	150	°C
Operating junction and storage temperature range	T _{stg}	-55 to +150	°C

●Thermal resistance

Daramatar	Cymah al	Values			l list
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R_{thJC}	-	-	1.48	°C/W
Thermal resistance, junction - ambient	R _{thJA}	-	-	40	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-	4	265	°C

● Electrical characteristics (T_a = 25°C)

Deremeter	Cumbal	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_D = 1mA$	600	-	-	V
Zero gate voltage drain current	I _{DSS}	$V_{DS} = 600V, V_{GS} = 0V$ $T_j = 25^{\circ}C$	-	-	100	μA
Gate - Source leakage current	I _{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$	-	-	±100	nA
Gate threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 4.5 \text{mA}$	5.0	6.0	7.0	V
Static drain - source on - state resistance	R _{DS(on)} *5	$V_{GS} = 15V, I_D = 12.5A$ $T_j = 25^{\circ}C$	-	0.140	0.182	Ω
Gate resistance	R _G	f = 1MHz, open drain	-	2.0	-	Ω

● Electrical characteristics (T_a = 25°C)

Davamatav	Cumphal	Conditions	Values			Unit
Parameter	Parameter Symbol Conditions		Min.	Тур.	Max.	Unit
Input capacitance	C _{iss}	V _{GS} = 0V	-	1900	-	
Output capacitance	C _{oss}	V _{DS} = 100V	-	115		
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	2.0	(_
Effective output capacitance energy related	C _{o(er)} *6	V _{GS} = 0V	-	85	5	pF
Effective output capacitance time related	C _{o(tr)} *7	V _{DS} = 0V to 480V	-	340	-	
Turn - on delay time	t _{d(on)} *5	$V_{DD} \simeq 300V$, $V_{GS} = 15V$		33	-	
Rise time	t,*5	I _D = 12.5A	1	24	-	no
Turn - off delay time	t _{d(off)} *5	R _L ≃ 24.3Ω	-	60	-	ns
Fall time	t _f *5	$R_G = 10\Omega$	-	18	-	

● Gate charge characteristics (T_a = 25°C)

Darameter	Symbol Conditions		Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Total gate charge	Q_g^{*5}	V _{DD} ≈ 300V	-	57	-	
Gate - Source charge	Q _{gs} *5	I _D = 25A	-	18.5	-	nC
Gate - Drain charge	Q _{gd} *5	V _{GS} = 15V	-	20.5	1	
Gate plateau voltage	V _(plateau)	$V_{DD} \simeq 300V$, $I_D = 25A$	-	9.8	1	V

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*3} L \simeq 50mH, V_{DD} = 50V, R_G = 25 Ω , starting T_i = 25°C

^{*4} Tc=25°C

^{*5} Pulsed

^{*6} Co(er) is a fixed capacitance that gives the same stored energy as Coss while V_{DS} is rising from 0 to 80% V_{DSS} .

^{*7} Co(tr) is a fixed capacitance that gives the same charging time as Coss while V_{DS} is rising from 0 to 80% V_{DSS} .

● Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Parameter	Symbol	Symbol Conditions		Values		
i alametei	Symbol	Conditions	Min.	Тур.	Max.	Unit
Source current	I _S *1	T - 25°C	-	-	25	A
Pulsed source current	I _{SP} *2	T _C = 25°C	-	-	75	A
Source-Drain voltage	V _{SD} *5	$V_{GS} = 0V, I_{S} = 25A$	-	-	1.7	>
Reverse recovery time	t _{rr} *5		-	90	-	ns
Reverse recovery charge	Q _{rr} *5	I _S = 25A di/dt = 100A/µs	· (?)	350	-	nC
Peak reverse recovery current	I _{.rr} *5) -	8.0	-	Α



• Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

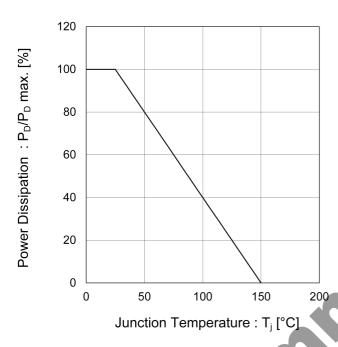


Fig.2 Drain Current Derating
Curve vs. Junction Temperature

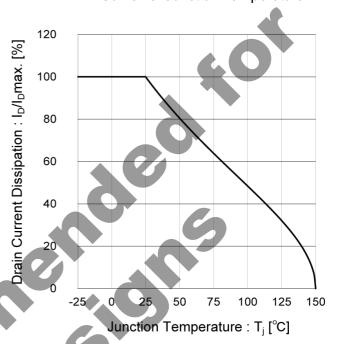


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

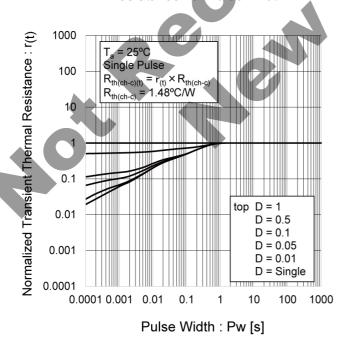
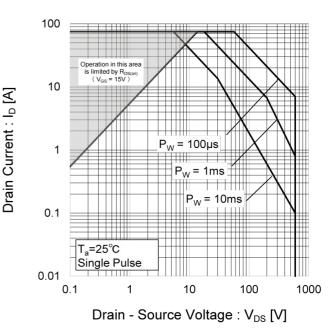


Fig.4 Maximum Safe Operating Area



• Electrical characteristic curves

Fig.5 Avalanche Energy Derating
Curve vs. Junction Temperature

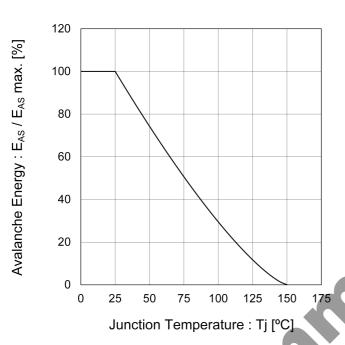


Fig.6 Normalized Breakdown Voltage vs. Junction Temperature

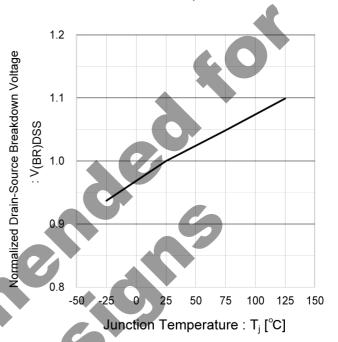


Fig.7 Typical Output Characteristics(I)

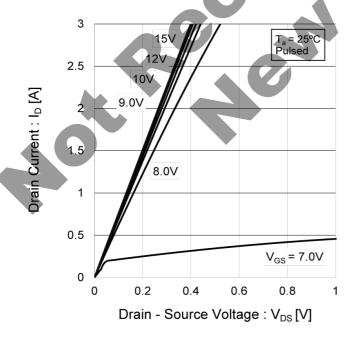
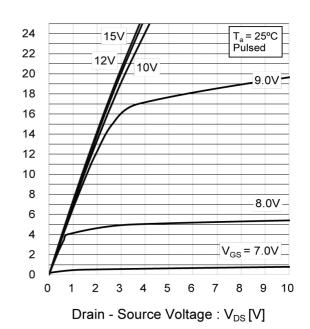


Fig.8 Typical Output Characteristics(II)



Drain Current : I_D [A]

Electrical characteristic curves

Fig.9 Typical Transfer Characteristics

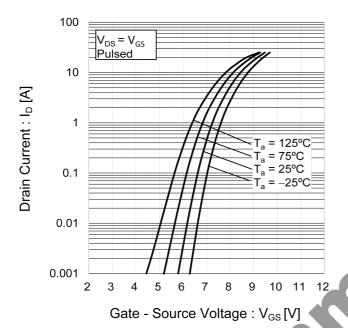
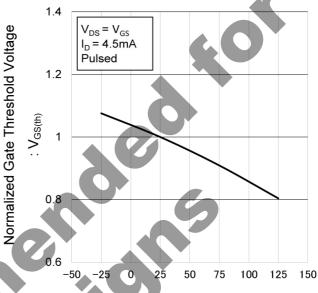
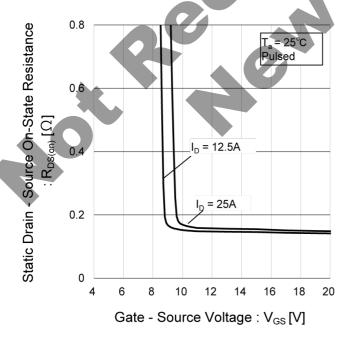


Fig.10 Normalized Gate Threshold. Voltage vs Junction Temperature

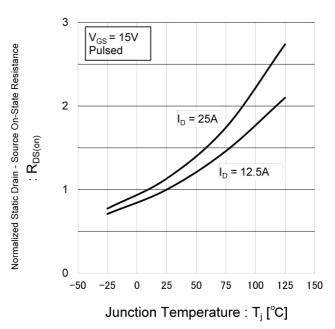


Junction Temperature : T_i [°C]

Fig.11 Static Drain - Source On - State Resistance vs. Gate Source Voltage



ig.12 Normalized Static Drain - Source On - State Resistance vs. Junction Temperature



Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Drain Current

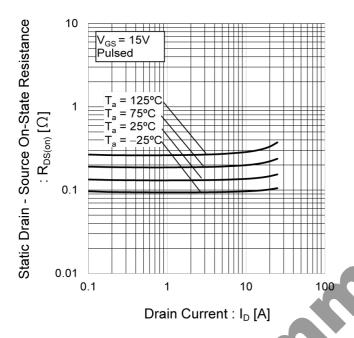


Fig.14 Typical Capacitance vs.
Drain - Source Voltage

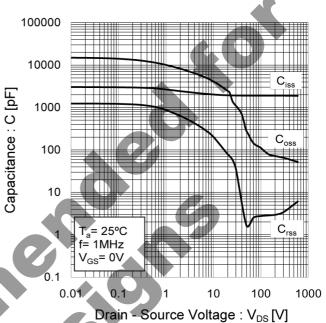


Fig.15 Typical Coss Stored Energy

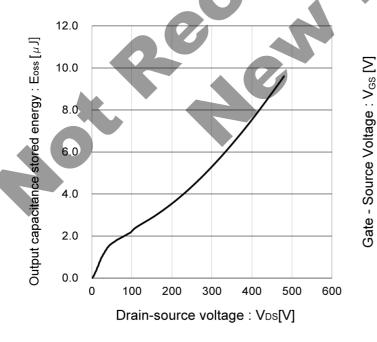
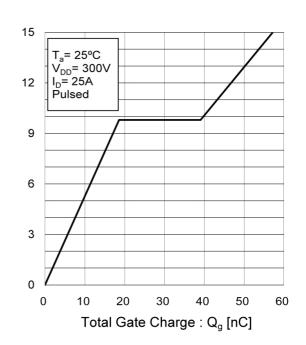


Fig.16 Typical Gate Charge



• Electrical characteristic curves

Fig.17 Inverse Diode Forward Current vs. Source - Drain Voltage

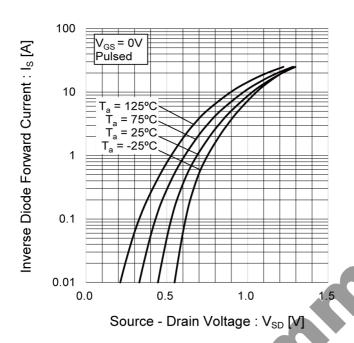
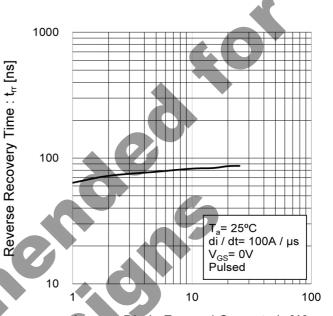


Fig.18 Reverse Recovery Time vs.
Inverse Diode Forward Current



Inverse Diode Forward Current : Is [A]

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

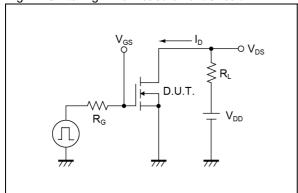


Fig.2-1 Gate Charge Measurement Circuit

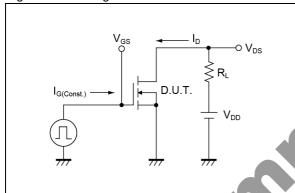


Fig.3-1 Avalanche Measurement Circuit

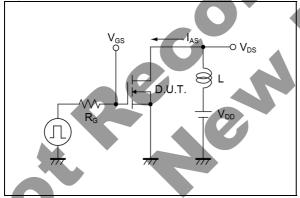


Fig.4-1 Diode Recovery Measurement Circuit

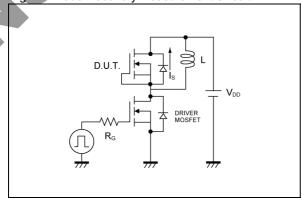


Fig.1-2 Switching Waveforms

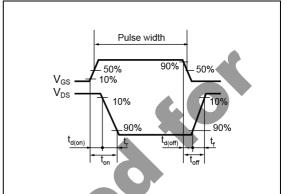


Fig.2-2 Gate Charge Waveform

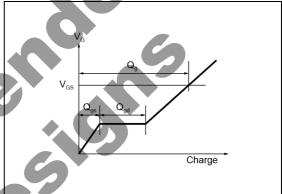


Fig.3-2 Avalanche Waveform

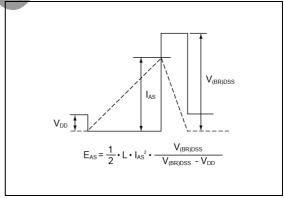
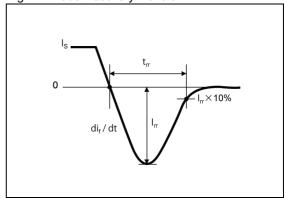
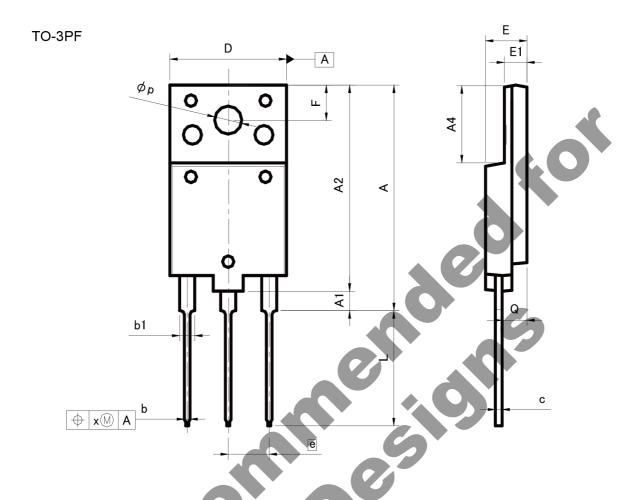


Fig.4-2 Diode Recovery Waveform



Dimensions



DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A	26.30	26.70	1.035	1.051
A1	2.30	2.70	0.091	0.106
A2	26.30	26.70	1.035	1.051
A4	9.80	10.20	0.386	0.402
b	0.65	0.95	0.026	0.037
b1	1.80	2.20	0.071	0.087
С	0.80	1.10	0.031	0.043
D	15.30	15.70	0.602	0.618
E	5.30	5.70	0.209	0.224
е	5.4	45	0.215	_
E1	2.80	3.20	0.110	0.126
F	4.30	4.70	0.169	0.185
L	14.60	15.00	0.575	0.591
р	3.40	3.80	0.134	0.150
Q	3.10	3.50	0.122	0.138
Х	_	0.50	_	0.020

Dimension in mm/inches

Notice

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 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
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